## NSN 5962-01-310-9493

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View Online at https://aerobasegroup.com/nsn/5962-01-310-9493 **Body Length:** 0.440 inches **Body Width:** 0.285 inches **Body Height:** 0.085 inches **Maximum Power Dissipation Rating:** 332.8 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and w/open collector and bipolar and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Case Outline Source And Designator:** F-5 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 flat leads Shelf Life: N/a

Demilitarization: Yes - demil/mli

**Unit Of Measure:** 

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